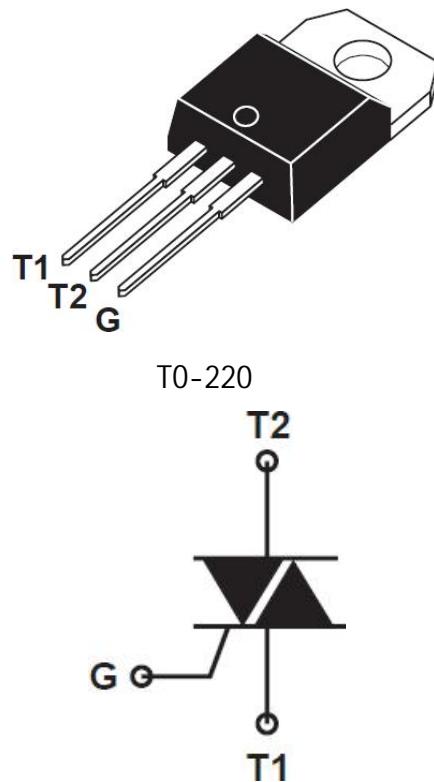


Triacs sensitive gate**BTA212-600B****GENERAL DESCRIPTION**

Passivated, sensitive gate triacs in a plastic envelope, intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants.

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

| Parameter | Symbol | Typ | Unit |
|--------------------------------------|------------------------|---------|------|
| Repetitive peak off-state voltages | V_{DRM} V_{RRM} | 600 | V |
| RMS on-state current | $I_{T(RMS)}$ | 12 | A |
| Non-repetitive peak on-state current | I_{TSM} | 95 | A |
| Max. Operating Junction Temperature | T_j | 110 | °C |
| Storage Temperature | T_{stg} | -45~150 | °C |

**ELECTRICAL CHARACTERISTICS (Ta = 25 °C)**

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|------------------------------------|------------------------|---|-----|-----|------|------|
| Repetitive peak off-state voltages | V_{DRM} V_{RRM} | | — | 600 | — | V |
| RMS on-state current | $I_{T(RMS)}$ | full sine wave; $T_{mb} \leq 107$ °C | — | 12 | — | A |
| On-state voltage | V_T | $I_T = 15$ A | — | 1.4 | 1.65 | V |
| Holding current | I_H | $V_D = 12$ V; $I_{GT} = 0.1$ A | — | — | 60 | mA |
| Gate trigger current | T2+G+ | I_{GT} $V_D = 12$ V; $I_T = 0.1$ A | — | — | 50 | mA |
| | T2+G- | | — | — | 50 | |
| | T2-G- | | — | — | 50 | |
| | T2-G+ | | — | — | 100 | |
| Latching current | T2+G+ | I_L $V_D = 12$ V; $I_{GT} = 0.1$ A | — | — | 60 | mA |
| | T2+G- | | — | — | 90 | |
| | T2-G- | | — | — | 60 | |
| | T2-G+ | | — | — | 90 | |
| Gate trigger voltage | V_{GT} | $V_D = 12$ V; $I_T = 0.1$ A | — | 0.7 | 1.5 | V |